BFP840FESD

Low Noise Amplifier for 5 to 6 GHz WLAN using BFP840FESD with Low Parts-Count

Application Note AN289
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2012-11-09
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Application Note AN289

Revision History: 2012-11-09

Previous Revision: Rev 1.0

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Last Trademarks Update 2011-11-11
Low Noise Amplifier for 5 to 6 GHz WLAN with Low Parts-Count

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1 Introduction

1.1 Wi-Fi®

Wireless Fidelity (Wi-Fi®) plays a major role in today’s communications by enabling constant connection in the 2.4 GHz and 5 GHz bands and broadband Internet access for users with laptops or devices equipped with wireless network interface while roaming within the range of fixed access points (AP) or a public hotspot. Different applications like home entertainment with wireless high-quality multimedia signal transmission, home networking notebooks, mass data storages and printers implement 5 – 6 GHz Wi-Fi® into their system to offer high-speed wireless connectivity.

When wider coverage areas are needed and especially when a higher order modulation scheme is used such as in emerging very high throughput wireless specifications like 256 Quadrature Amplitude Modulation (256-QAM) in IEEE 802.11ac, the SNR requirements for both the AP and the client are more stringent. For this kind of high-speed high data rate wireless communication standards it is essential to ensure the quality of the link path. Major performance criteria of these equipments have to be fulfilled: sensitivity, strong signal capability and interference immunity. Below a general application diagram of a WLAN system is shown.

![General Application Diagram of a WLAN System](image-url)

**Figure 1** 5 – 6 GHz Wi-Fi® Wireless LAN (WLAN, IEEE802.11a/n) and WiMAX (IEEE802.16e) Front-End
In order to increase the system sensitivity, an excellent low noise amplifier (LNA) in front of the receiver is mandatory, especially in an environment with very weak signal strength and because of the insertion loss of the SPDT switch and the Bandpass Filter (BPF) or diplexer. The typical allowed receiver chain Noise Figure (NF) of approx. 2 dB can only be achieved by using a high-gain low noise amplifier.

In addition, strong signal environment can exist when the equipment is next to a transmitter. In that case, the LNA must be linear enough, i.e. have high 1dB compression point. This avoids saturation, degradation of the gain and increased noise figure.

This application note is focusing on the LNA block, but Infineon does also support with RF-switches, TVS-diodes for ESD protection and RF Schottky diodes for power detection.

### 1.2 Device Overview: BFP840FESD

The BFP840FESD is a discrete hetero-junction bipolar transistor (HBT) specifically designed for high performance 5 GHz band low noise amplifier (LNA) solutions for Wi-Fi connectivity applications. It combines the 80 GHz $f_T$ silicon-germanium:carbide (SiGe:C) B9HFM process with special device geometry engineering to reduce the parasitic capacitance between substrate and transistor that degrades high-frequency characteristics, resulting in an inherent input matching and a major improvement in power gain 5 GHz band together with a low noise figure performance that is industry's best.

The BFP840FESD has an integrated 1.5kV HBM ESD protection which makes the device robust against electrostatic discharge and extreme RF input power. The device offers its high performance at low current and voltage and is especially well-suited for portable battery powered applications in which energy efficiency is a key requirement.

The BFP840FESD is housed in flat-leads TSFP-4-1 package. Further variants are available in industry standard visible-leads SOT343 package (BFP840ESD) and in the low-height 0.31mm TSLP-3-9 package (BFR840L3RHESD) specially fitting into modules.
2 Low Parts Count Low Noise Amplifier for 5 to 6 GHz WLAN with BFP840FESD

This application note presents the measurement results of the Low Noise Amplifier using BFP840FESD for 5100 MHz to 5900 MHz WLAN applications. The circuit schematic shown in Figure 2 doesn’t require any external input matching elements.

It’s a low parts count solution which requires only 8 passive 0402 SMD components and brings gain from 18.4 dB to 17.4 dB over the frequency band. The gain is approx. 2 dB higher compared to BFP740F (AN168). The noise figure varies from 1.05 dB to 1.0 dB (SMA and PCB losses are subtracted) over the frequency band.

The circuit achieves an input and output return loss of 10 dB. Furthermore, the circuit is unconditionally stable from 10 MHz to 15 GHz. However, Proper RF grounding on PCB has to be ensured in order to achieve stability k-factor > 1 above 11 GHz (Figure 18).

At 5.5 GHz, using two tones spacing of 1 MHz, the output third intercept point OIP3 reaches 15.3 dBm. Besides, we obtain 1dB input compression point IP1dB of -11.5 dBm.
3 Overview

Device: BFP840FESD
Application: Low Noise Amplifier for 5 to 6 GHz WLAN with Low Parts-Count
PCB Marking: BFP840FESD TSFP-4 M12051302

4 Summary of Measurement Results

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Symbol</th>
<th>Value</th>
<th>Unit</th>
<th>Note/Test Condition</th>
</tr>
</thead>
<tbody>
<tr>
<td>DC Voltage</td>
<td>Vcc</td>
<td>3.0</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>DC Current</td>
<td>Icc</td>
<td>14</td>
<td>mA</td>
<td></td>
</tr>
<tr>
<td>Frequency Range</td>
<td>Freq</td>
<td>5100</td>
<td>5500</td>
<td>5900</td>
</tr>
<tr>
<td>Gain</td>
<td>G</td>
<td>18.9</td>
<td>18.3</td>
<td>17.7</td>
</tr>
<tr>
<td>Noise Figure</td>
<td>NF</td>
<td>1.05</td>
<td>1.05</td>
<td>1.08</td>
</tr>
<tr>
<td>Input Return Loss</td>
<td>RLin</td>
<td>11.1</td>
<td>11.6</td>
<td>10.8</td>
</tr>
<tr>
<td>Output Return Loss</td>
<td>RLout</td>
<td>11.4</td>
<td>10.6</td>
<td>11.7</td>
</tr>
<tr>
<td>Reverse Isolation</td>
<td>IRev</td>
<td>26.5</td>
<td>26.2</td>
<td>25.9</td>
</tr>
<tr>
<td>Input P1dB</td>
<td>IP1dB</td>
<td>-9.9</td>
<td>dBm</td>
<td></td>
</tr>
<tr>
<td>Output P1dB</td>
<td>OP1dB</td>
<td>+7.4</td>
<td>dBm</td>
<td></td>
</tr>
<tr>
<td>Input IP3</td>
<td>IIP3</td>
<td>-0.7</td>
<td>dBm</td>
<td></td>
</tr>
</tbody>
</table>
| Output IP3          | OIP3   | +17.6 | dBm  | Power @ Input: -25 dBm  
|                     |        |       |      | f1 = 5500 MHz, f2 = 5501 MHz                          |
| Stability           | k      | > 1.0 | --   | Stability measured from 10MHz to 15GHz               |
A proper RF grounding is required to ensure the LNA performance. Please refer to Chapter 7 for the layout proposal.

PCB Marking: BFP840FESD M12051302
PCB Board Material = Standard FR4
Layer spacing (top RF to internal ground plane): 0.2 mm

Table 2  Bill-of-Materials

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Value</th>
<th>Unit</th>
<th>Size</th>
<th>Manufacturer</th>
<th>Comment</th>
</tr>
</thead>
<tbody>
<tr>
<td>C1</td>
<td>22</td>
<td>pF</td>
<td>0402</td>
<td>Various</td>
<td>Input DC block</td>
</tr>
<tr>
<td>C2</td>
<td>1.0</td>
<td>pF</td>
<td>0402</td>
<td>Various</td>
<td>Output DC block &amp; output matching</td>
</tr>
<tr>
<td>C3</td>
<td>1.0</td>
<td>pF</td>
<td>0402</td>
<td>Various</td>
<td>Output matching</td>
</tr>
<tr>
<td>C4</td>
<td>33</td>
<td>pF</td>
<td>0402</td>
<td>Various</td>
<td>RF decoupling / blocking cap</td>
</tr>
<tr>
<td>L1</td>
<td>1.8</td>
<td>nH</td>
<td>0402</td>
<td>Murata LQP15M series</td>
<td>Output matching and biasing to the Collector</td>
</tr>
<tr>
<td>R1</td>
<td>27</td>
<td>kΩ</td>
<td>0402</td>
<td>Various</td>
<td>DC biasing</td>
</tr>
<tr>
<td>R2</td>
<td>51</td>
<td>Ω</td>
<td>0402</td>
<td>Various</td>
<td>Stability improvement</td>
</tr>
<tr>
<td>R3</td>
<td>51</td>
<td>Ω</td>
<td>0402</td>
<td>Various</td>
<td>DC biasing (provides DC negative feedback to stabilize DC operating point over temperature variation, transistor $h_{FE}$ variation, etc.)</td>
</tr>
<tr>
<td>Q1</td>
<td>TSFP-4-1</td>
<td></td>
<td>Infineon Technologies</td>
<td>BFP840FESD SiGe:C Heterojunction Bipolar RF Transistor</td>
<td></td>
</tr>
</tbody>
</table>

Figure 2  Schematic Diagram of the used Circuit
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**Figure 4** Wideband Insertion Power Gain of the 5-6 GHz WLAN LNA with BFP840FESD
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Figure 6  Reverse Isolation of the 5-6 GHz WLAN LNA with BFP840FESD
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7 Evaluation Board and Layout Information

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Figure 17  Zoom-In Picture of the BFP840FESD 5-6 GHz WLAN LNA Evaluation Board
Figure 18  Layout Proposal for RF Grounding of the 5-6 GHz WLAN LNA with BFP840FESD

Figure 19  PCB Layer Information
8 Authors

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9 Remark

The graphs are generated with the simulation program AWR Microwave Office®.